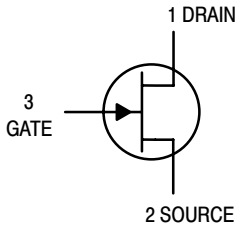
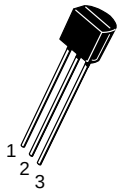
JFET Switching
N–Channel — Depletion



2N5555

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Drain–Source Voltage	V_{DS}	25	Vdc
Drain–Gate Voltage	V_{DG}	25	Vdc
Gate–Source Voltage	V_{GS}	25	Vdc
Forward Gate Current	I_{GF}	10	mAdc
Total Device Dissipation @ T_C = 25°C Derate above 25°C	P_D	350 2.8	mW mW/°C
Junction Temperature Range	T_J	–65 to +150	°C
Storage Temperature Range	T_{stg}	–65 to +150	°C



CASE 29–11, STYLE 5
TO–92 (TO–226AA)

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Characteristic	Symbol	Min	Max	Unit
OFF CHARACTERISTICS				
Gate–Source Breakdown Voltage (I_G = 10 μAdc, V_{DS} = 0)	$V_{(BR)GSS}$	25	—	Vdc
Gate Reverse Current (V_{GS} = 15 Vdc, V_{DS} = 0)	I_{GSS}	—	1.0	nAdc
Drain Cutoff Current (V_{DS} = 12 Vdc, V_{GS} = –10 V) (V_{DS} = 12 Vdc, V_{GS} = –10 V, T_A = 100°C)	$I_{D(off)}$	— —	10 2.0	nAdc μAdc
ON CHARACTERISTICS				
Zero–Gate–Voltage Drain Current(1) (V_{DS} = 15 Vdc, V_{GS} = 0)	I_{DSS}	15	—	mAdc
Gate–Source Forward Voltage ($I_{G(f)}$ = 1.0 mAdc, V_{DS} = 0)	$V_{GS(f)}$	—	1.0	Vdc
Drain–Source On–Voltage (I_D = 7.0 mAdc, V_{GS} = 0)	$V_{DS(on)}$	—	1.5	Vdc
Static Drain–Source On Resistance (I_D = 0.1 mAdc, V_{GS} = 0)	$r_{DS(on)}$	—	150	Ohms

1. Pulse Test: Pulse Width < 300 μs, Duty Cycle < 3.0%.

SMALL–SIGNAL CHARACTERISTICS

Small–Signal Drain–Source “ON” Resistance (V_{GS} = 0, I_D = 0, f = 1.0 kHz)	$r_{ds(on)}$	—	150	Ohms
Input Capacitance (V_{DS} = 15 Vdc, V_{GS} = 0, f = 1.0 MHz)	C_{iss}	—	5.0	pF
Reverse Transfer Capacitance (V_{DS} = 0, V_{GS} = 10 Vdc, f = 1.0 MHz)	C_{rss}	—	1.2	pF

SWITCHING CHARACTERISTICS

Turn–On Delay Time	(V_{DD} = 10 Vdc, $I_{D(on)}$ = 7.0 mAdc, $V_{GS(on)}$ = 0, $V_{GS(off)}$ = –10 Vdc) (See Figure 1)	$t_{d(on)}$	—	5.0	ns
Rise Time		t_r	—	5.0	ns
Turn–Off Delay Time	(V_{DD} = 10 Vdc, $I_{D(on)}$ = 7.0 mAdc, $V_{GS(on)}$ = 0, $V_{GS(off)}$ = –10 Vdc) (See Figure 1)	$t_{d(off)}$	—	15	ns
Fall Time		t_f	—	10	ns

© Semiconductor Components Industries, LLC, 2001

November, 2001 – Rev. 3
Publication Order Number:
2N5555/D

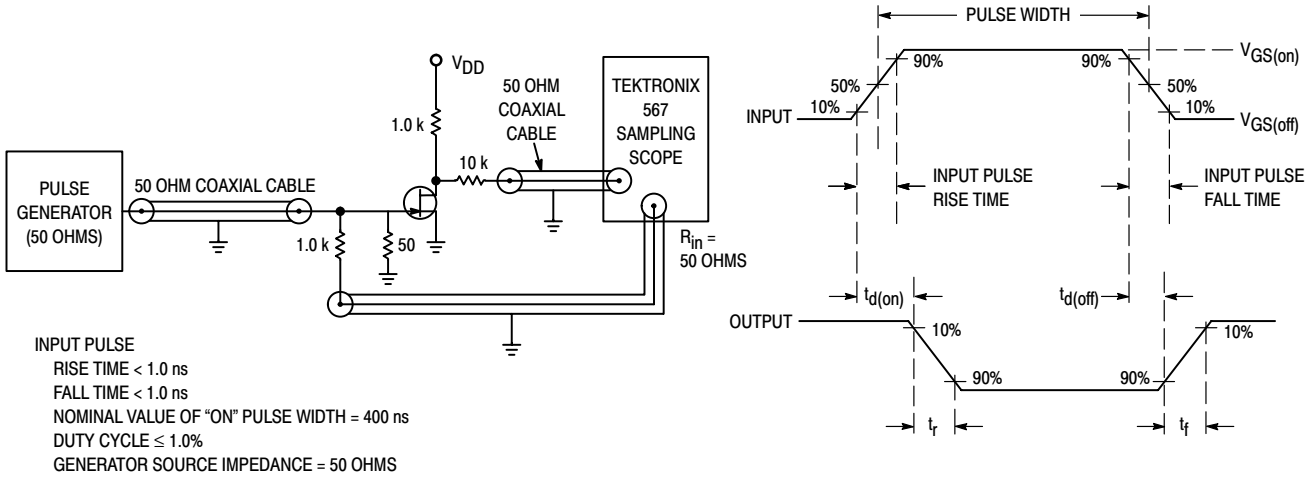


Figure 1. Switching Times Test Circuit

COMMON SOURCE CHARACTERISTICS

ADMITTANCE PARAMETERS

(V_{DS} = 15 Vdc, $T_{channel}$ = 25°C)

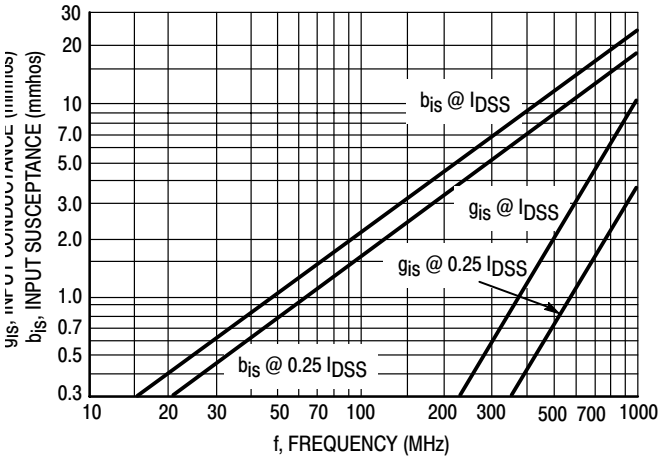


Figure 2. Input Admittance (y_{is})

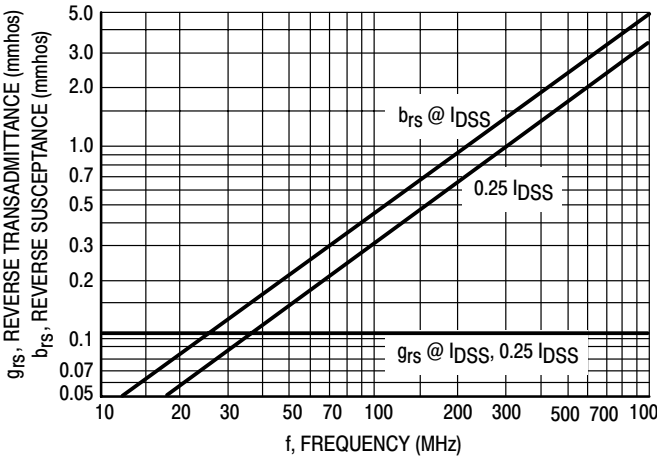


Figure 3. Reverse Transfer Admittance (y_{rs})

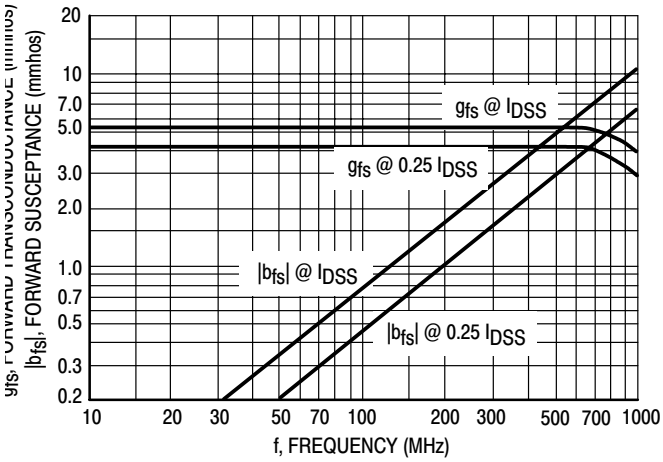


Figure 4. Forward Transadmittance (y_{fs})

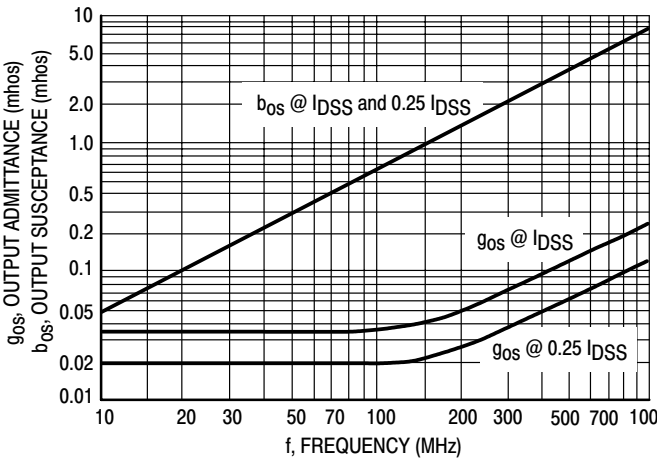


Figure 5. Output Admittance (y_{os})

COMMON SOURCE CHARACTERISTICS

S–PARAMETERS

(V_{DS} = 15 Vdc, $T_{channel}$ = 25°C, Data Points in MHz)

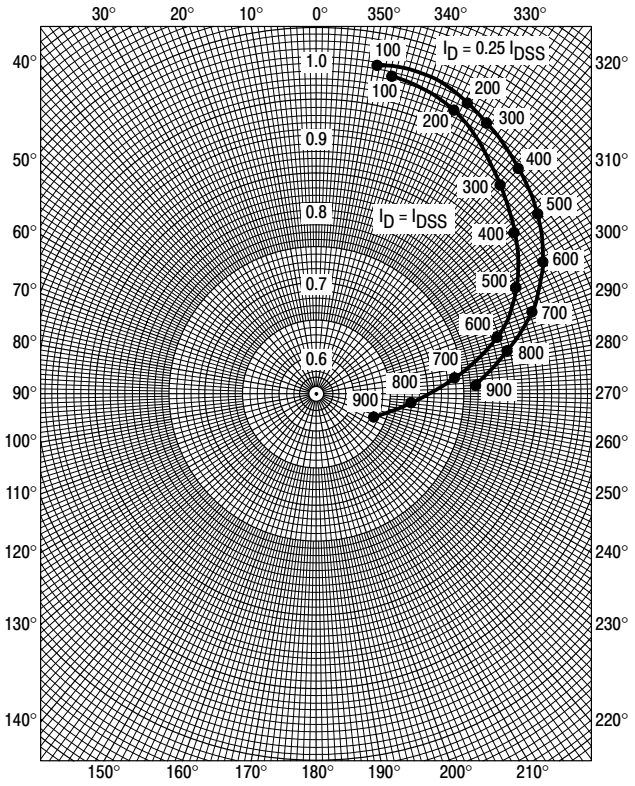


Figure 6. S_{11s}

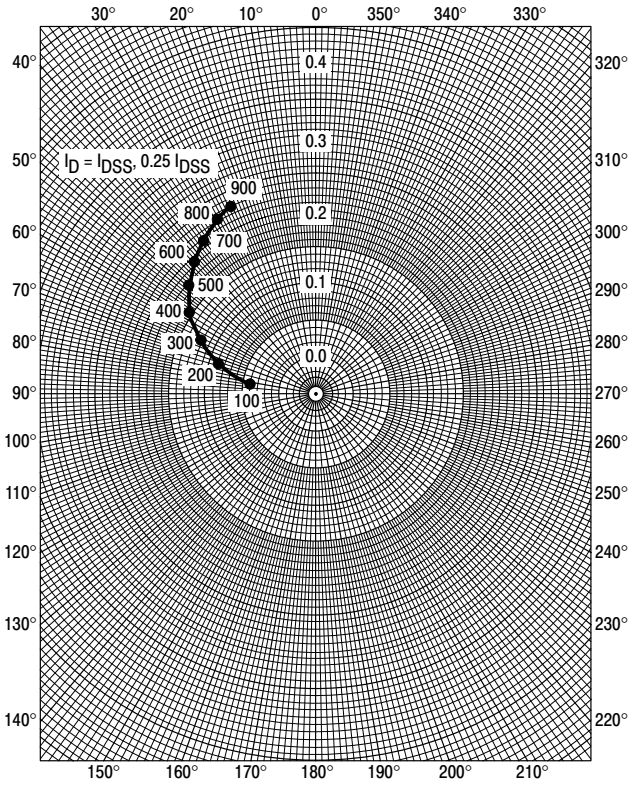


Figure 7. S_{12s}

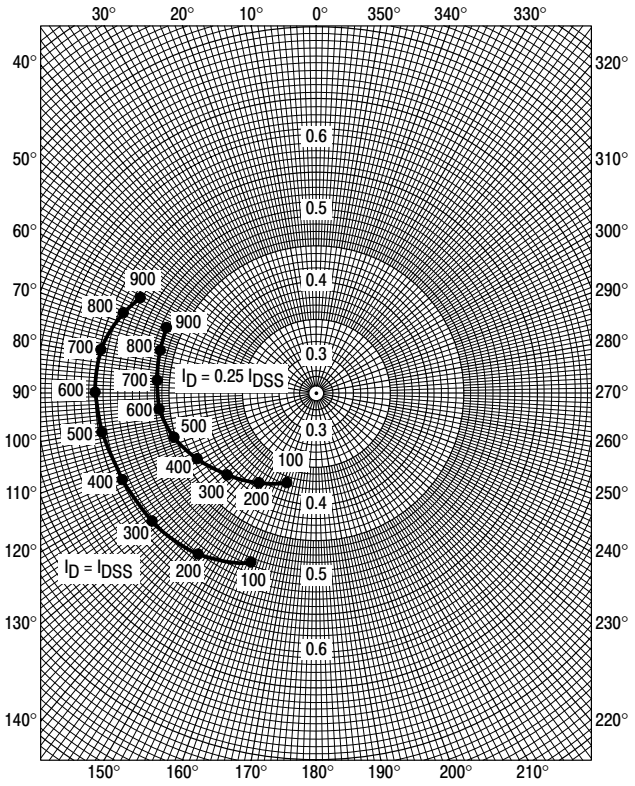


Figure 8. S_{21s}

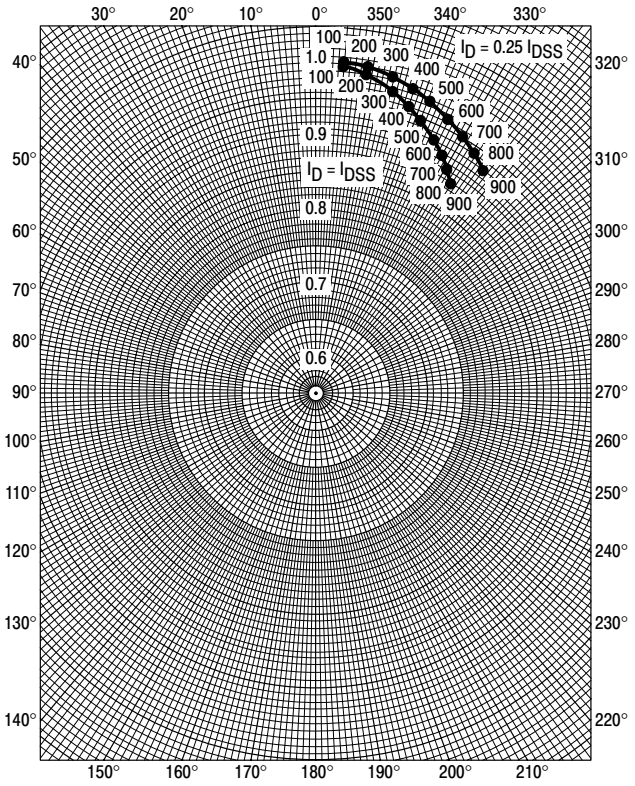


Figure 9. S_{22s}

COMMON GATE CHARACTERISTICS

ADMITTANCE PARAMETERS

(V_{DG} = 15 Vdc, $T_{channel}$ = 25°C)

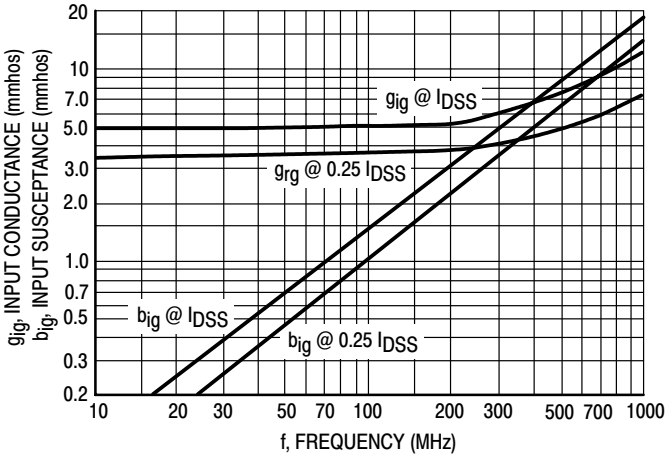


Figure 10. Input Admittance (y_{ig})

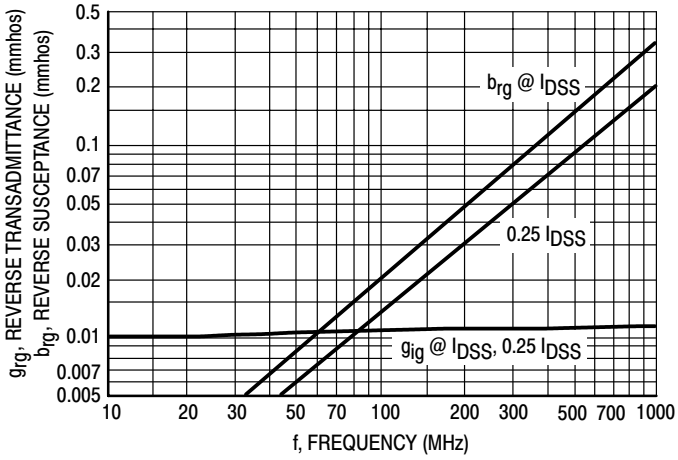


Figure 11. Reverse Transfer Admittance (y_{rg})

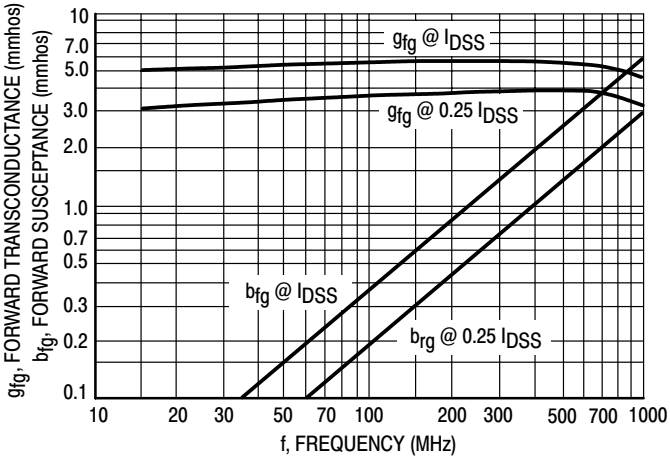


Figure 12. Forward Transfer Admittance (y_{fg})

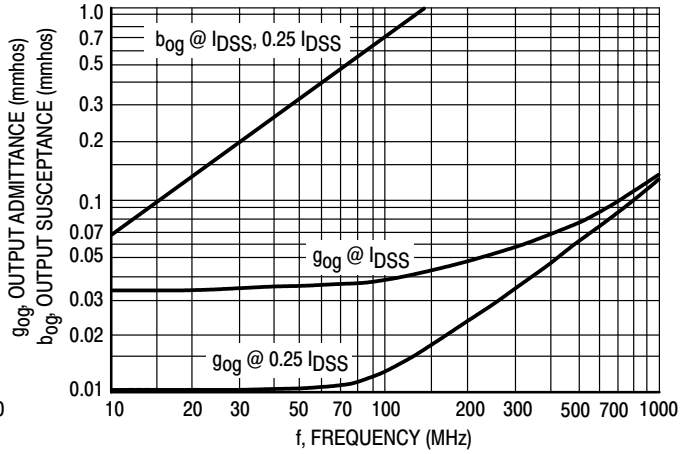


Figure 13. Output Admittance (y_{og})

COMMON GATE CHARACTERISTICS

S–PARAMETERS

(V_{DS} = 15 Vdc, $T_{channel}$ = 25°C, Data Points in MHz)

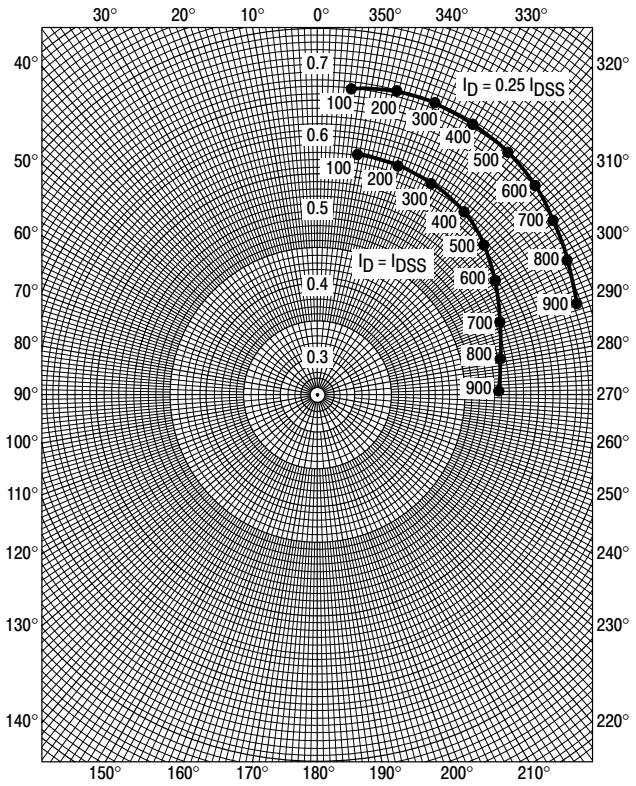


Figure 14. S_{11g}

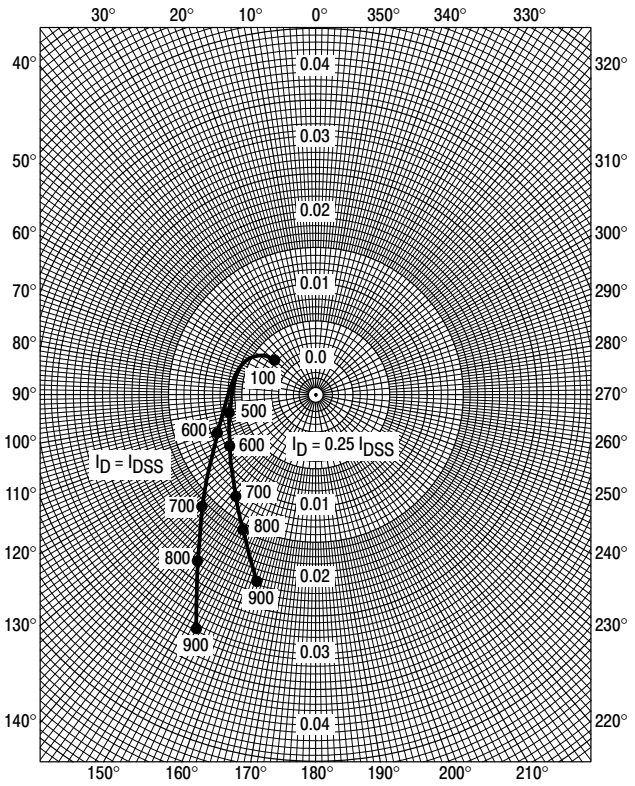


Figure 15. S_{12g}

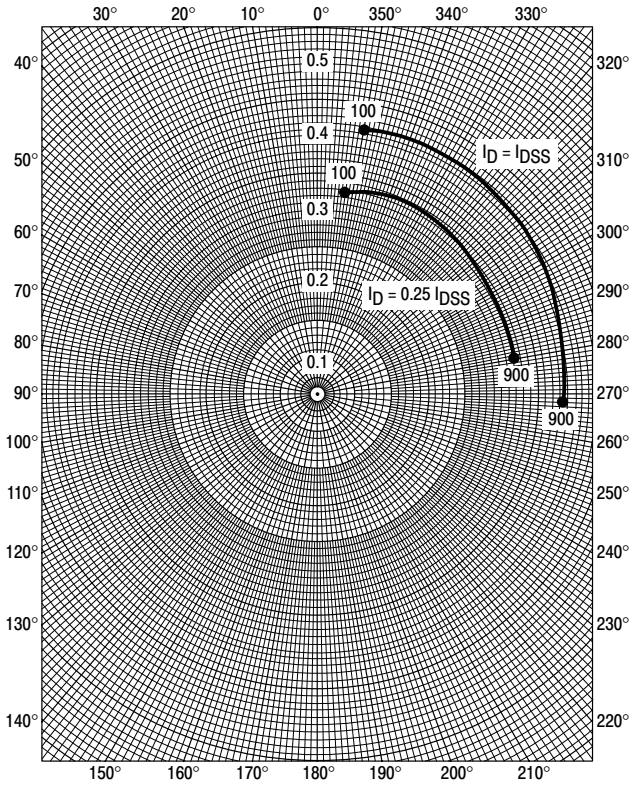


Figure 16. S_{21g}

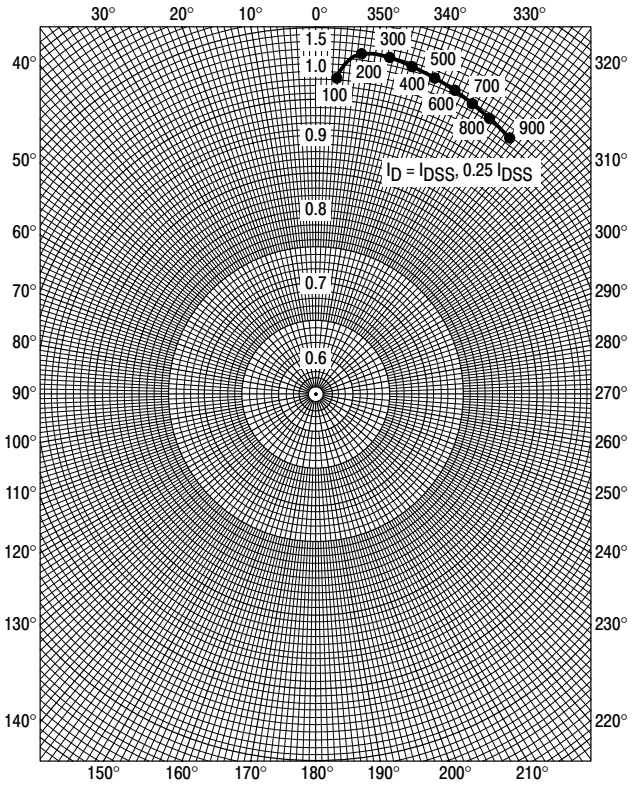
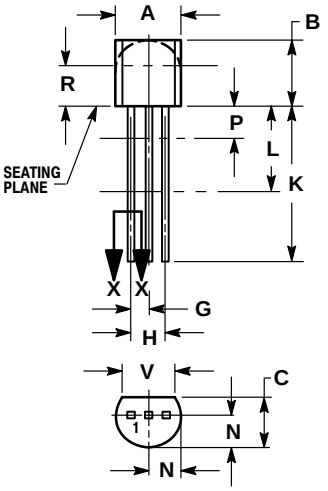
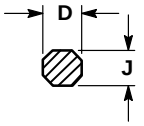


Figure 17. S_{22g}

PACKAGE DIMENSIONS

TO–92 (TO–226AA)
CASE 29–11
ISSUE AL





SECTION X–X

NOTES:
1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
2. CONTROLLING DIMENSION: INCH.
3. CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
4. LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS	
DIM	MIN	MAX	MIN	MAX
A	0.175	0.205	4.45	5.20
B	0.170	0.210	4.32	5.33
C	0.125	0.165	3.18	4.19
D	0.016	0.021	0.407	0.533
G	0.045	0.055	1.15	1.39
H	0.095	0.105	2.42	2.66
J	0.015	0.020	0.39	0.50
K	0.500	---	12.70	---
L	0.250	---	6.35	---
N	0.080	0.105	2.04	2.66
P	---	0.100	---	2.54
R	0.115	---	2.93	---
V	0.135	---	3.43	---

STYLE 5:
PIN 1. DRAIN
2. SOURCE
3. GATE

Notes

ON Semiconductor and  are trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer.

PUBLICATION ORDERING INFORMATION

Literature Fulfillment:
Literature Distribution Center for ON Semiconductor
P.O. Box 5163, Denver, Colorado 80217 USA
Phone: 303–675–2175 or 800–344–3860 Toll Free USA/Canada
Fax: 303–675–2176 or 800–344–3867 Toll Free USA/Canada
Email: ONlit@hibbertco.com

N. American Technical Support: 800–282–9855 Toll Free USA/Canada

JAPAN: ON Semiconductor, Japan Customer Focus Center
4–32–1 Nishi–Gotanda, Shinagawa–ku, Tokyo, Japan 141–0031
Phone: 81–3–5740–2700
Email: r14525@onsemi.com

ON Semiconductor Website: http://onsemi.com

For additional information, please contact your local
Sales Representative.